



WESTCODE SEMICONDUCTORS


 Technical
Publication

TN630C

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Convertor Grade Capsule Thyristor Type N630C

 1500 amperes average: up to 3600 volts V_{RRM}

Ratings (Maximum values at 125°C T_j unless stated otherwise)

RATING	CONDITIONS	SYMBOL	
Average on-state current	Half sine wave $\left\{ \begin{array}{l} 55^{\circ}\text{C heatsink temperature} \\ \text{(double side cooled)} \\ 85^{\circ}\text{C heatsink temperature} \\ \text{(single side cooled)} \end{array} \right.$	$I_{T(AV)}$	1500A 630A
R.M.S. on-state current	25°C heatsink temperature, double side cooled	$I_T (RMS)$	2950A
Continuous on-state current	25°C heatsink temperature, double side cooled	I_T	2580A
Peak one-cycle surge (non-repetitive) on state current	10ms duration, 60% V_{RRM} re-applied	$I_{TSM(1)}$	23000A
	10ms duration, $V_R \leq 10$ volts	$I_{TSM(2)}$	25000A
Maximum permissible surge energy	10ms duration, $V_R \leq 10$ volts	$I^2t(2)$	3130000A ² s
	3ms duration, $V_R \leq 10$ volts	I^2t	2300000A ² s
Peak forward gate current	Anode positive with respect to cathode	I_{FGM}	20A
Peak forward gate voltage	Anode positive with respect to cathode	V_{FGM}	22V
Peak reverse gate voltage		V_{RGM}	5V
Average gate power		P_G	4W
Peak gate power	100μs. pulse width	P_{GM}	120W
Rate of rise of off-state voltage	To 80% V_{DRM} gate open-circuit	dv/dt	* 200V/μs
Rate of rise of on-state current (repetitive)	$\left\{ \begin{array}{l} \text{Gate drive 20 volts, 20 ohms with } t_r \leq 1\mu s. \\ \text{Anode voltage } \leq 80\% V_{DRM} \end{array} \right.$	$di/dt(1)$	150A/μs
Rate of rise of on-state current (non-repetitive)		$di/dt(2)$	300A/μs
Operating temperature range		T_{hs}	-40 + 125°C
Storage temperature range		T_{stg}	-40 + 150°C

Characteristics (Maximum values at 125°C T_j unless stated otherwise)

CHARACTERISTIC	CONDITIONS	SYMBOL	
Peak on-state voltage	At 3220 A, I_{TM}	V_{TM}	2.17V
Forward conduction threshold voltage		V_O	1.04V
Forward conduction slope resistance		r	0.35mΩ
Repetitive peak off-state current	At V_{DRM}	I_{DRM}	150mA
Repetitive peak reverse current	At V_{RRM}	I_{RRM}	150mA
Maximum gate current required to fire all devices	$\left\{ \begin{array}{l} V_A = 6 \text{ V, } I_A = 2 \text{ A at } 25^{\circ}\text{C } T_j \end{array} \right.$	I_{GT}	300mA
Maximum gate voltage required to fire all devices		V_{GT}	3V
Maximum holding current		I_H	1A
Maximum gate voltage which will not trigger any device		V_{GD}	0.25V
Thermal resistance, junction to heatsink, for a device with a maximum forward volt drop characteristic	Double side cooled Single side cooled	$R_{th(j-hs)}$	0.02°C/W 0.04°C/W

VOLTAGE CODE		H26	H28	H30	H32	H34	H36		
Repetitive peak voltages	V_{RRM} V_{DRM}	2600	2800	3000	3200	3400	3600		
Non-repetitive peak off-state voltage	V_{DSM}								
Non-repetitive peak reverse blocking voltage	V_{RSM}	2700	2900	3100	3300	3500	3700		

Ordering Information (Please quote device code as explained below – 8 digits)

N	6	3	0	C	●	●	●	
					Voltage code (see ratings)			Typical code: N630CH36 = 3600 V_{RRM} 3600 V_{DRM} , 200 V/μs. dv/dt to 80% V_{DRM}

 * Other values of dv/dt may be available.

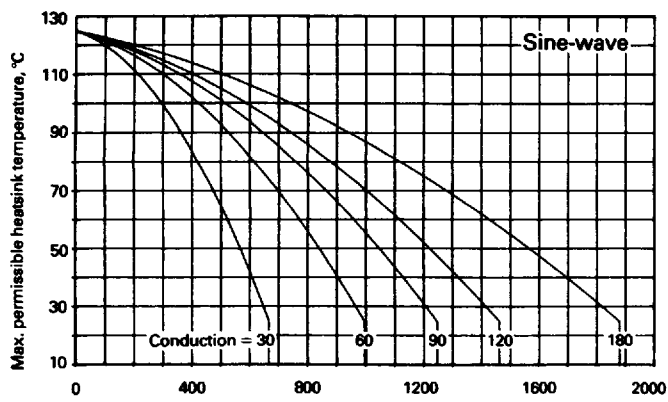


Figure 1 Dissipation and heatsink temperature v. current (Double side cooled)

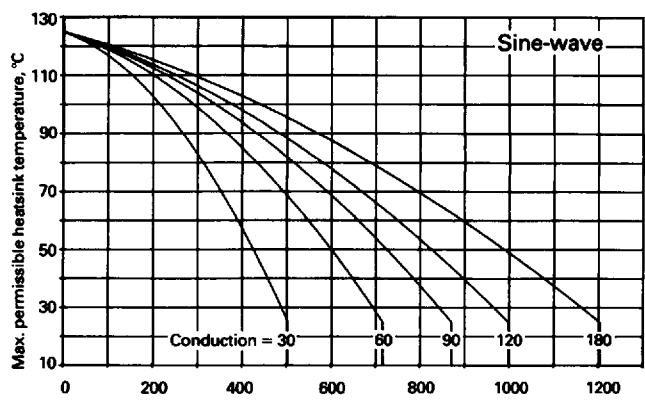


Figure 2 Dissipation and heatsink temperature v. current (Single side cooled)

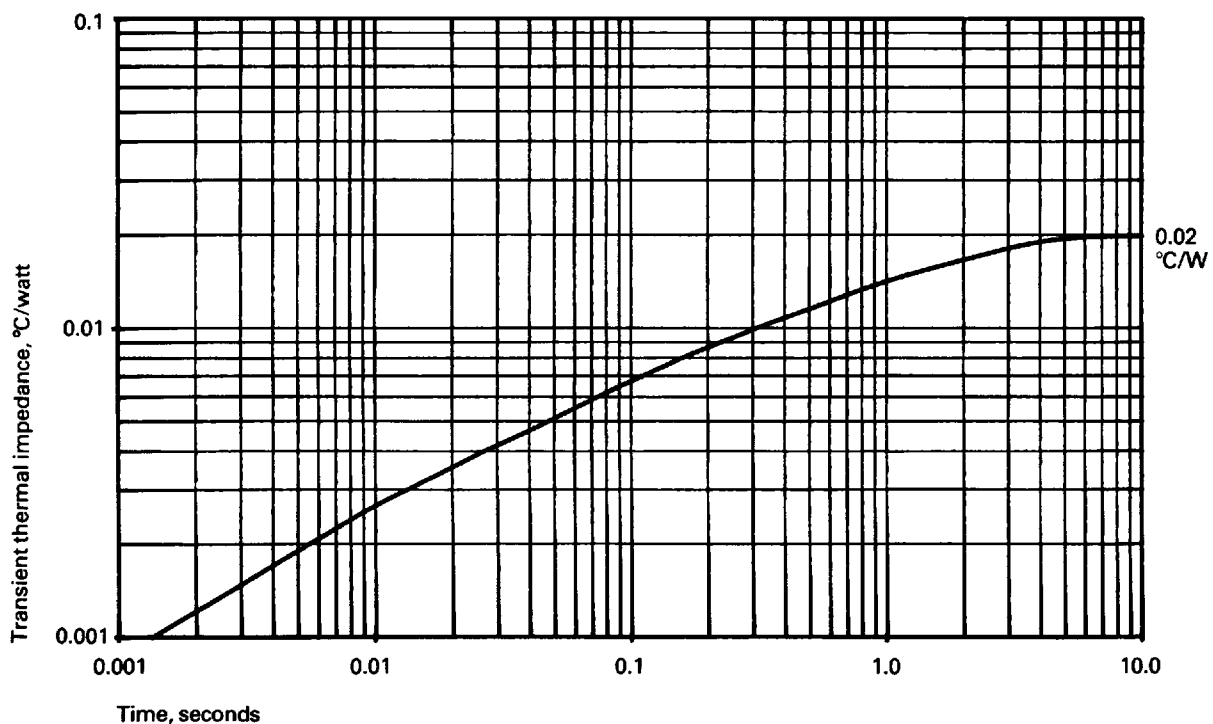
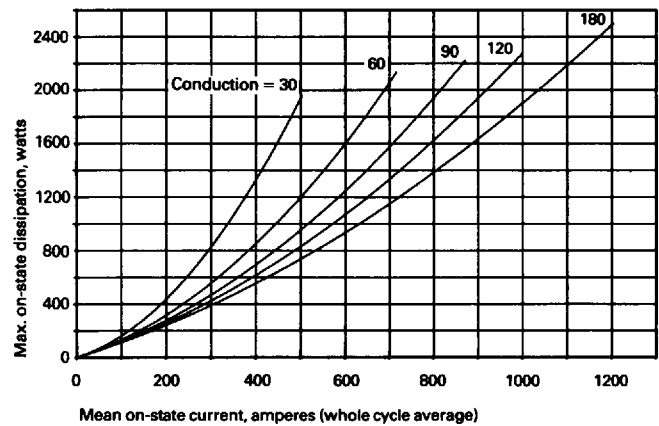
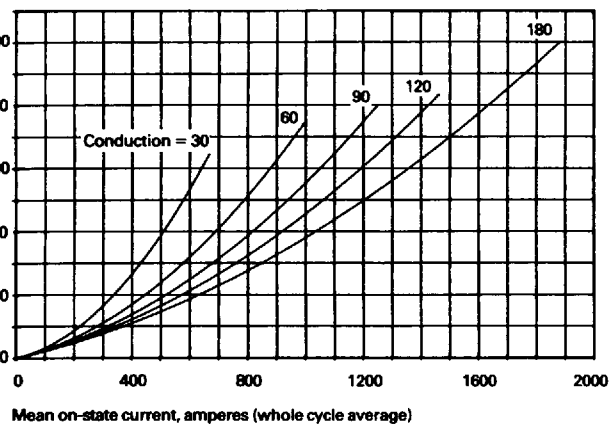


Figure 3 Junction to heatsink thermal impedance

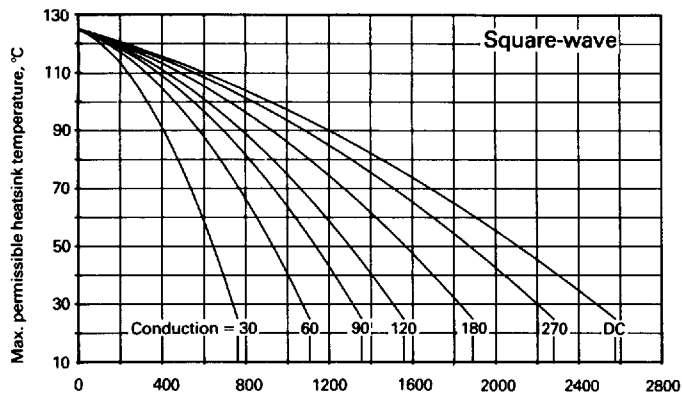


Figure 4 Dissipation and heatsink temperature
v. current (Double side cooled)

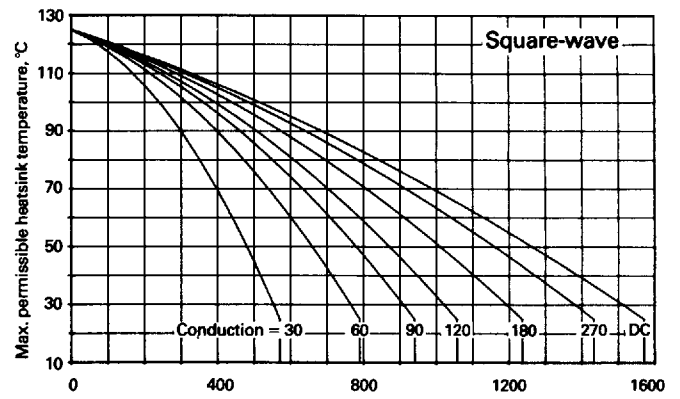


Figure 5 Dissipation and heatsink temperature
v. current (Single side cooled)

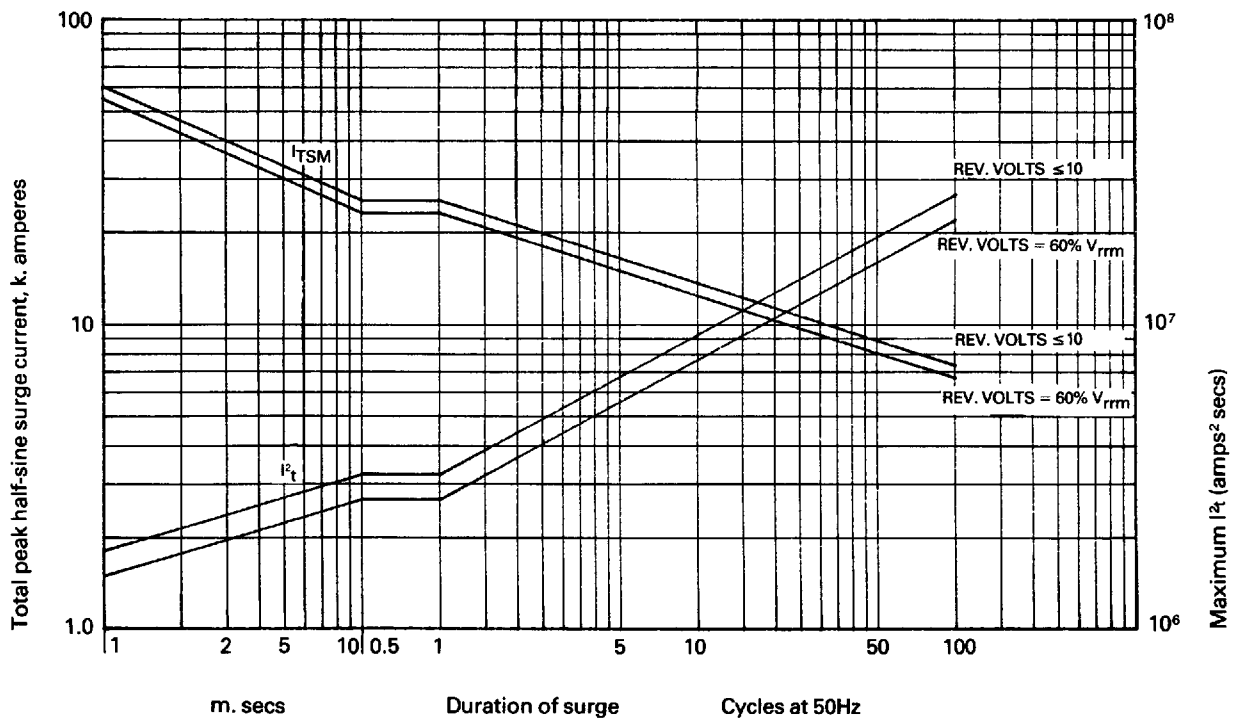
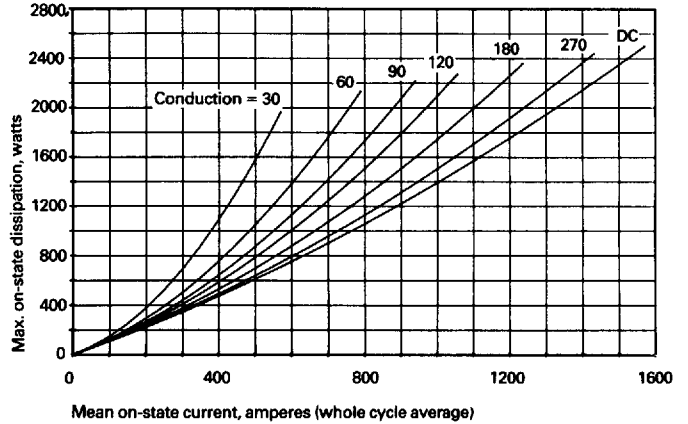
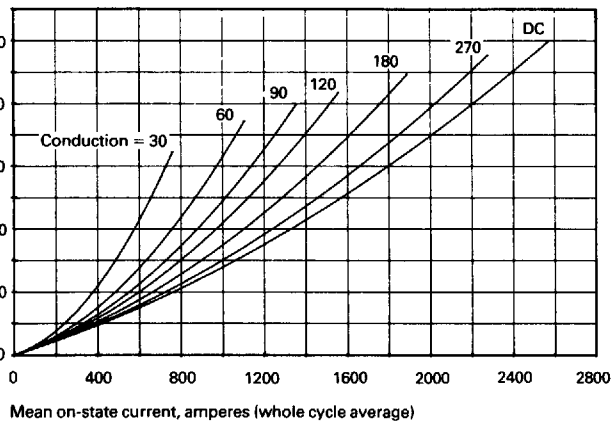


Figure 6 Max. non-repetitive surge current at initial junction temperature 125°C.

(gate may temporarily lose control of firing angle)

Note: This rating must not be interpreted as an intermittent rating

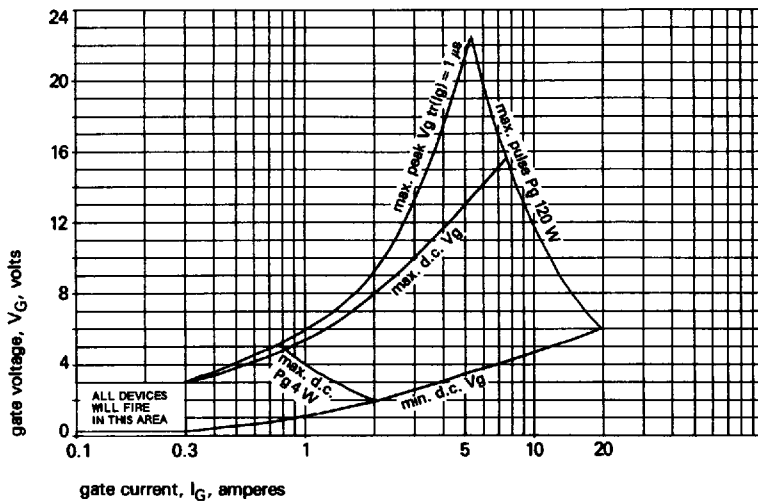


Figure 7 Gate characteristics at 25°C junction temperature

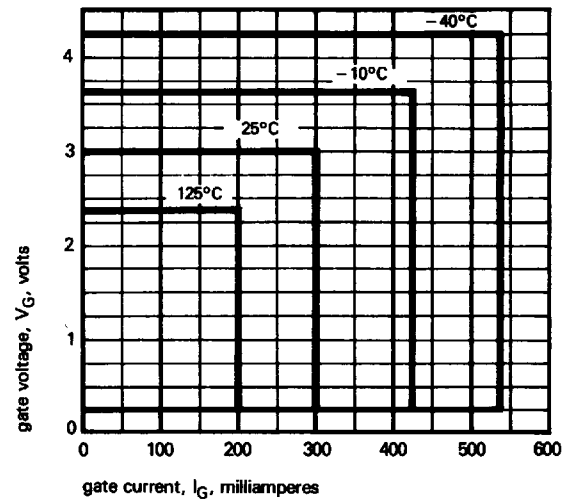


Figure 8 Gate triggering characteristics
Trigger points of all thyristors lie within the areas shown

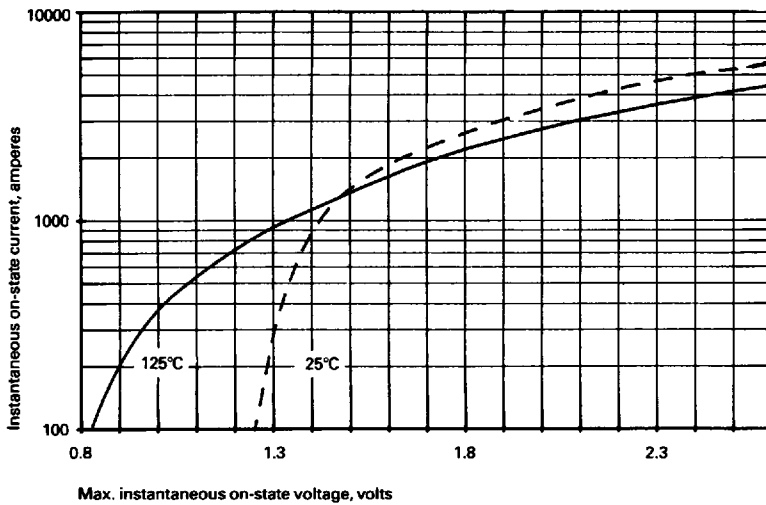
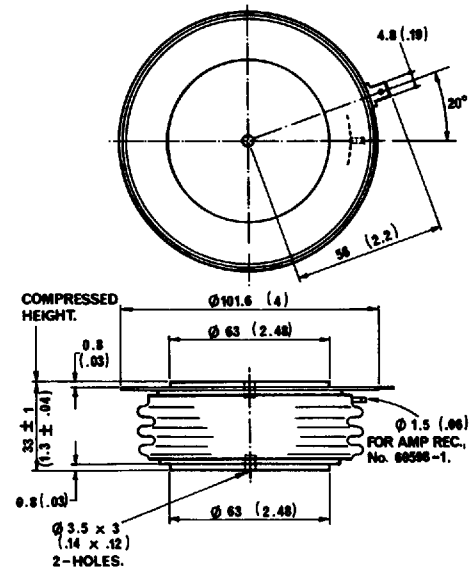


Figure 9 Limit on-state characteristic



Dimensions in mm (inches)
Mounting force: 2700–3400 Kgf
Weight: 1000 grams

In the interest of product improvement, Westcode reserves the right to change specifications at any time without notice.

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